MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

TK40P03M1

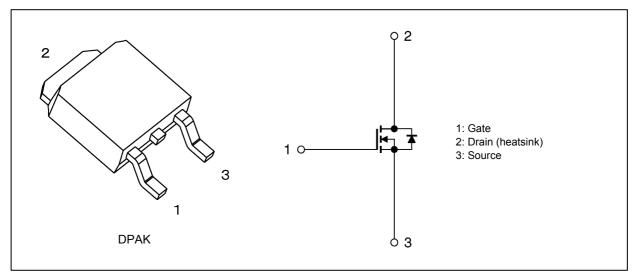
1. Applications

- DC-DC Converters
- Desktop PCs

2. Features

- (1) High-speed switching
- (2) Low gate charge: $Q_{SW} = 5.7 \text{ nC}$ (typ.)
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 8.3 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (4) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (5) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_{D} = 0.1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | | | Rating | Unit |
|--|----------|------------------|------------|------|
| Drain-source voltage | | V _{DSS} | 30 | V |
| Gate-source voltage | | V _{GSS} | ±20 | |
| Drain current (DC) | (Note 1) | I _D | 40 | A |
| Drain current (pulsed) | (Note 1) | I _{DP} | 120 | |
| Power dissipation (T _c = 25 | 5°C) | PD | 33 | W |
| Single-pulse avalanche energy | (Note 2) | E _{AS} | 42 | mJ |
| Avalanche current | | I _{AR} | 40 | A |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature | | T _{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---------------------------------------|-----------------------|------|------|
| Channel-to-case thermal resistance | R _{th(ch-c)} | 3.78 | °C/W |
| Channel-to-ambient thermal resistance | R _{th(ch-a)} | 125 | |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_DD = 24 V, T_ch = 25°C (initial), L = 20 μ H, R_G = 25 Ω , I_{AR} = 40 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

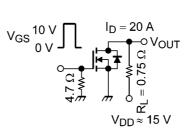
6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|-----|------|------|------|
| Gate leakage current | I _{GSS} | V_{GS} = ±20 V, V_{DS} = 0 V | _ | _ | ±0.1 | μA |
| Drain cut-off current | I _{DSS} | V _{DS} = 30 V, V _{GS} = 0 V | — | _ | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 30 | — | — | V |
| | V _{(BR)DSX} | I _D = 10 mA, V _{GS} = -20 V | 15 | _ | _ | |
| Gate threshold voltage | V _{th} | V _{DS} = 10 V, I _D = 0.1 mA | 1.3 | _ | 2.3 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 4.5 V, I _D = 20 A | | 11.1 | 14.4 | mΩ |
| | | V _{GS} = 10 V, I _D = 20 A | | 8.3 | 10.8 | |

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-----|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | | 1150 | _ | pF |
| Reverse transfer capacitance | C _{rss} |] | | 85 | _ | |
| Output capacitance | C _{oss} |] | | 260 | _ | |
| Gate resistance | r _g | V_{DS} = 10 V, V_{GS} = 0 V, f = 5 MHz | _ | 2.9 | 4.4 | Ω |
| Switching time (rise time) | tr | See Figure 6.2.1. | _ | 15 | _ | ns |
| Switching time (turn-on time) | t _{on} |] | | 21 | _ | |
| Switching time (fall time) | t _f |] | | 14 | _ | |
| Switching time (turn-off time) | t _{off} | 1 | | 54 | | |



Duty \leq 1%, t_w = 10 μ s

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------|------------------|--|-----|------|-----|------|
| Total gate charge (gate-source plus | Qg | $V_{DD} \approx 24$ V, V_{GS} = 10 V, I_D = 40 A | _ | 17.5 | _ | nC |
| gate-drain) | | $V_{DD} \approx 24$ V, V_{GS} = 5 V, I_D = 40 A | — | 9.4 | — | |
| Gate-source charge 1 | Q _{gs1} | $V_{DD} \approx 24$ V, V_{GS} = 10 V, I_D = 40 A | _ | 4.1 | — | |
| Gate-drain charge | Q _{gd} | | _ | 3.5 | _ | |
| Gate switch charge | Q _{SW} | | | 5.7 | | |

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-----------------------------------|---------|------------------|---|-----|------|------|------|
| Reverse drain current (pulsed) (1 | Note 3) | I _{DRP} | _ | | _ | 120 | А |
| Diode forward voltage | | V_{DSF} | I _{DR} = 40 A, V _{GS} = 0 V | _ | _ | -1.2 | V |

Note 3: Ensure that the channel temperature does not exceed 150°C.

7. Marking

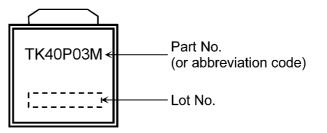
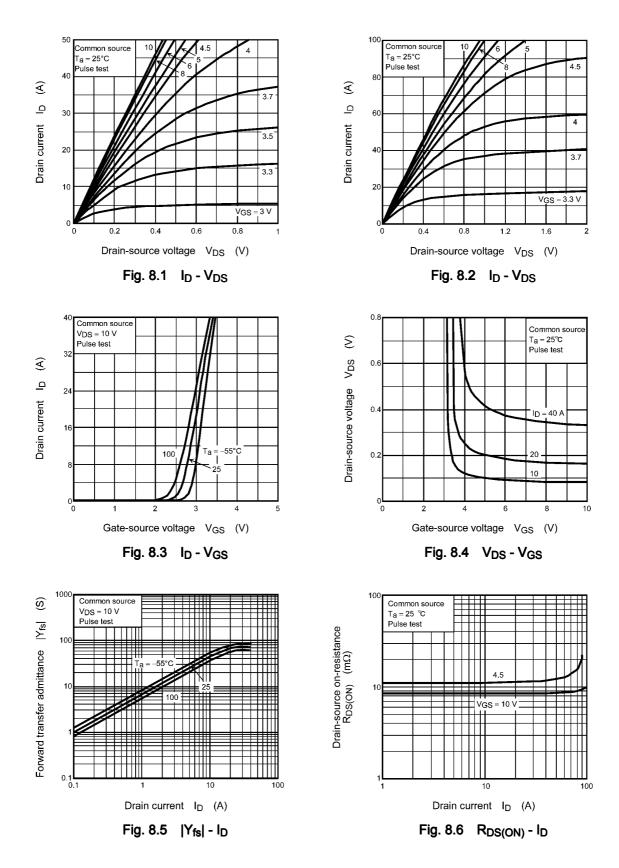


Fig. 7.1 Marking

8. Characteristics Curves (Note)



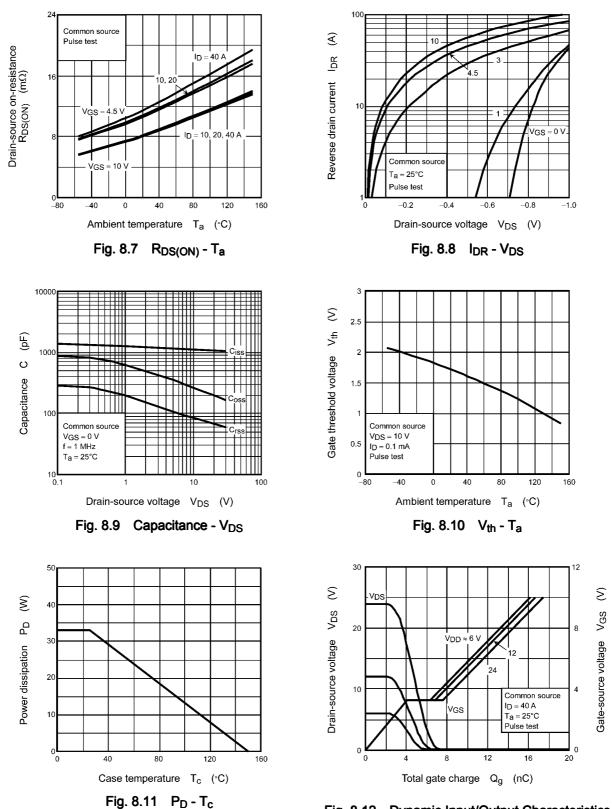


Fig. 8.12 Dynamic Input/Output Characteristics

(Guaranteed Maximum)

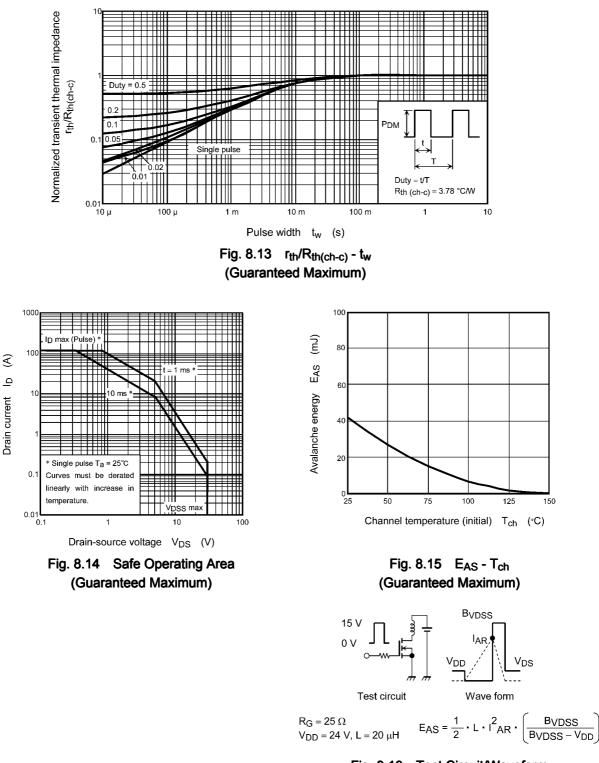


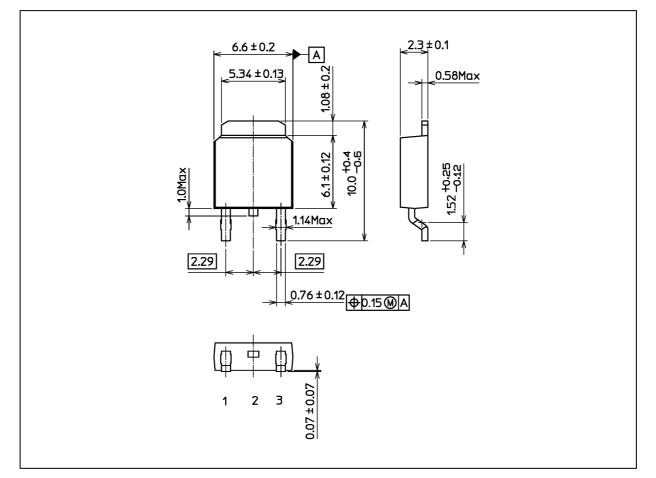
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TK40P03M1

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

| | Package Name(s) |
|-----------------|-----------------|
| TOSHIBA: 2-7K1S | |
| Nickname: DPAK | |

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